Pb Free Plating Product

# MUR1620FCA/MUR1640FCA/MUR1660FCA

16.0 Ampere Insulated Common Anode Ultra Fast Recovery Rectifiers

**Features**

- ✶ Fast switching for high efficiency
- ✶ Low forward voltage drop
- ✶ High current capability
- ✶ Low reverse leakage current
- ✶ High surge current capability

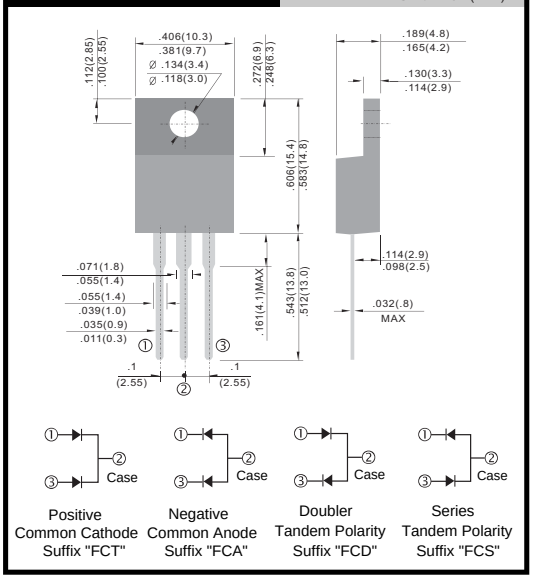
Application

- ✶ Automotive Inverters and Solar Inverters
- ✶ Plating Power Supply,SMPS and UPS
- ✶ Car Audio Amplifiers and Sound Device Systems

**Mechanical Data**

- ✶ Case: ITO-220AB full plastic isolated package
- ✶ Epoxy: UL 94V-0 rate flame retardant
- ✶ Terminals: Solderable per MIL-STD-202 method 208
- ✶ Polarity: As marked on diode body
- ✶ Mounting position: Any
- ✶ Weight: 2.0 gram approximately

**ITO-220AB** Unit : inch (mm)




## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| | SYMBOL | MUR1620FCA | MUR1640FCA | MUR1660FCA | UNIT |
|---|---|---|---|---|---|
| Maximum Recurrent Peak Reverse Voltage | $V_{RRM}$ | 200 | 400 | 600 | V |
| Maximum RMS Voltage | $V_{RMS}$ | 140 | 280 | 420 | V |
| Maximum DC Blocking Voltage | $V_{DC}$ | 200 | 400 | 600 | V |
| Maximum Average Forward Rectified Current $T_C$=100°C (Total Device 2x8A=16A) | $I_{F(AV)}$ | 16.0 | | | A |
| Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method) | $I_{FSM}$ | 175 | 150 | | A |
| Maximum Instantaneous Forward Voltage @ 8.0 A (Per Diode/Per Leg) | $V_F$ | 0.98 | 1.3 | 1.7 | V |
| Maximum DC Reverse Current @$T_J$=25°C<br>At Rated DC Blocking Voltage @$T_J$=125°C | $I_R$ | 5.0<br>100 | | | μA<br>μA |
| Maximum Reverse Recovery Time (Note 1) | Trr | 35 | | | nS |
| Typical junction Capacitance (Note 2) | $C_J$ | 90 | | | pF |
| Typical Thermal Resistance (Note 3) | $R_{\theta JC}$ | 2.0 | | | °C/W |
| Operating Junction and Storage Temperature Range | $T_J$, $T_{STG}$ | -55 to + 150 | | | °C |

NOTES : (1) Reverse recovery test conditions IF= 0.5A, R= 1.0A, Irr = 0.25A.
(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.
(3) Thermal Resistance junction to case.



© 1995 Thinki Semiconductor Co., Ltd.



Download from alldatasheet.com

FIG.1 - FORWARD CURRENT DERATING CURVE

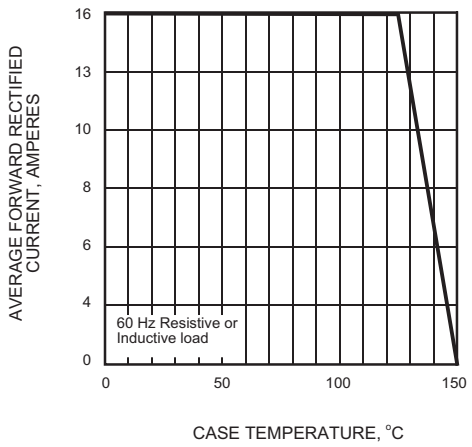



FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

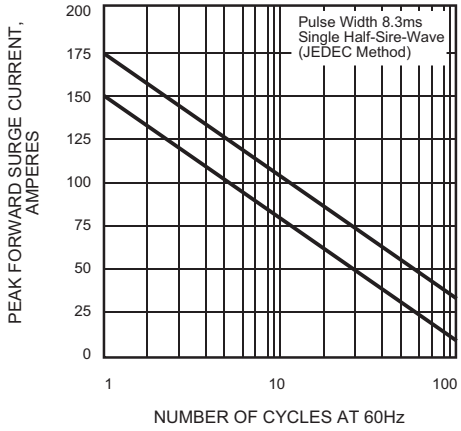



FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

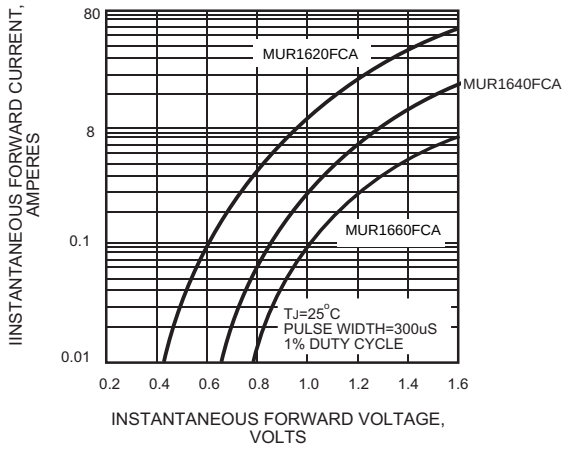



FIG.4 - TYPICAL REVERSE CHARACTERISTICS

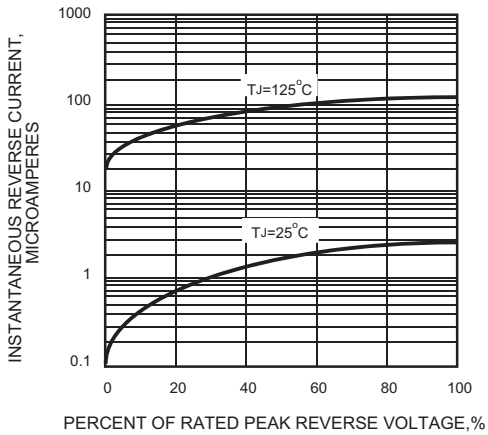
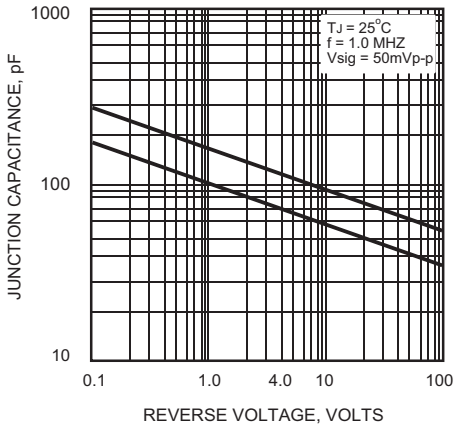



FIG.5 - TYPICAL JUNCTION CAPACITANCE






© 1995 Thinki Semiconductor Co., Ltd.

http://www.thinkisemi.com.tw/

Download from alldatasheet.com